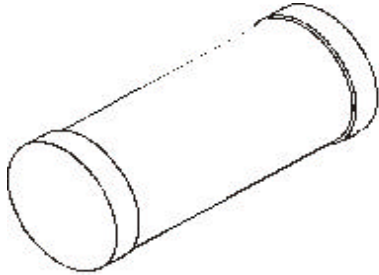


**SILICON DIAC  
 BIDIRECTIONAL TRIGGER DIODE  
 GLASS PASSIVATED PNPN DEVICE**

**CLLDB3**

**SOD - 80C  
 Mini MELF (LL-34)**



Functioning as a Trigger Diode with a Fixed Voltage Reference, CLLDB3 can be used in Conjunction with Triacs for Simplified Gate Control Circuits or as a Starting Element in Fluorescent Lamp Ballasts

**ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless specified otherwise))**

| DESCRIPTION  | SYMBOL        | VALUE        | UNIT               |
|--|---------------|--------------|--------------------|
| Power Dissipation on Printed Circuit (L=10mm) ( $T_a=50^\circ\text{C}$ )                 | $P_{tot}$     | 150          | mW                 |
| Up to $T_a = 50^\circ\text{C}$ and Mounted on a Ceramic Substrate of 10mm x 10mm x 0.6mm | $P_{tot}$     | 120          | mW                 |
| Repetitive Peak on-State Current ( $t_p=20\text{ms}$ , $f=100\text{Hz}$ )                | $I_{TRM}$     | 2            | A                  |
| Storage Temperature Range  | $T_{stg}$     | - 40 to +125 | $^\circ\text{C}$   |
| Junction Temperature Range   | $T_j$         | - 40 to +110 | $^\circ\text{C}$   |
| <b>THERMAL RESISTANCE</b>  |               |              |                    |
| Junction to Ambient in free air  | $R_{th(j-a)}$ | 400          | $^\circ\text{C/W}$ |
| Junction-Leads   | $R_{th(j-l)}$ | 150          | $^\circ\text{C/W}$ |

**ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ\text{C}$  unless specified otherwise)**

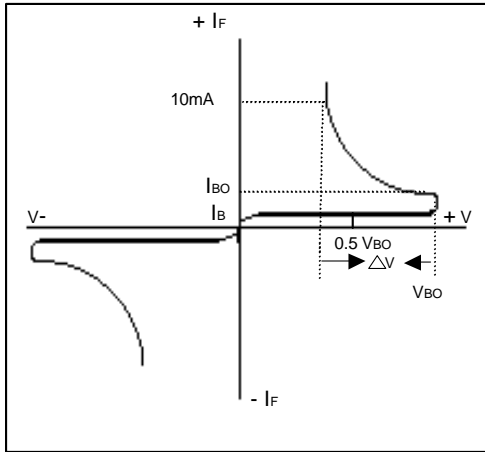
| DESCRIPTION                 | SYMBOL                    | TEST CONDITIONS  | MIN     | MAX     | UNIT          |
|-----------------------------|---------------------------|--|---------|---------|---------------|
| * Breakover Voltage         | $V_{BO}$                  | ** C = 22nF<br>see diagram 1   | 28      | 36      | V             |
| Breakover Voltage Symmetry  | $[ +V_{BO}  -  -V_{BO} ]$ | ** C = 22nF<br>see diagram 1   |         | $\pm 3$ | V             |
| * Dynamic Breakover Voltage | $ \Delta V_{\pm} $        | $\Delta I = [I_{BO} \text{ to } I_F = 10\text{mA}]$<br>see diagram 1 | 5       |         | V             |
| * Output Voltage            | $V_O$                     | see diagram 2  | 5       |         | V             |
| * Breakover Current         | $I_{BO}$                  | ** C = 22nF  |         | 50      | $\mu\text{A}$ |
| * Rise Time                 | $t_r$                     | see diagram 3  | TYP 1.5 |         | $\mu\text{s}$ |
| * Leakage Current           | $I_B$                     | $V_B = 0.5 V_{BO} \text{ max}$<br>see diagram 1                      |         | 10      | $\mu\text{A}$ |

\* Electrical characteristic applicable in both forward and reverse directions

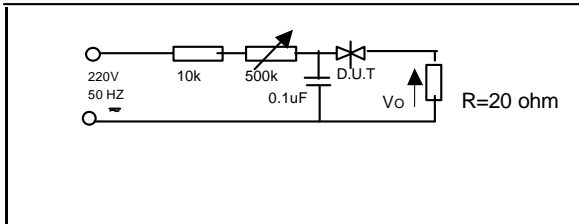
\*\* Connected in parallel with the devices.

**CLLDB3**

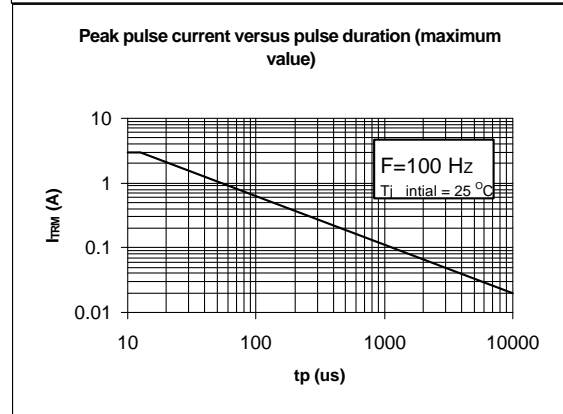
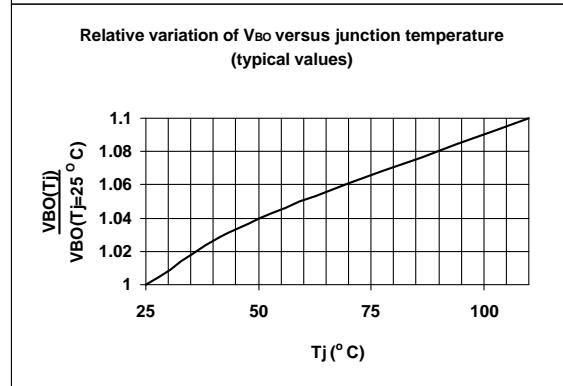
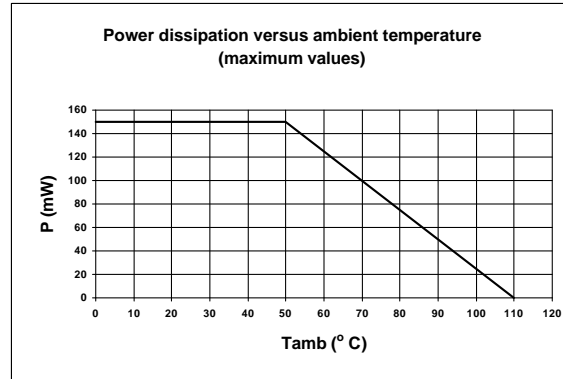
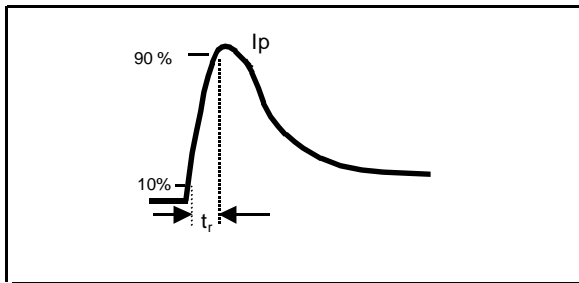
**DIAGRAM 1** :Current-voltage characteristics



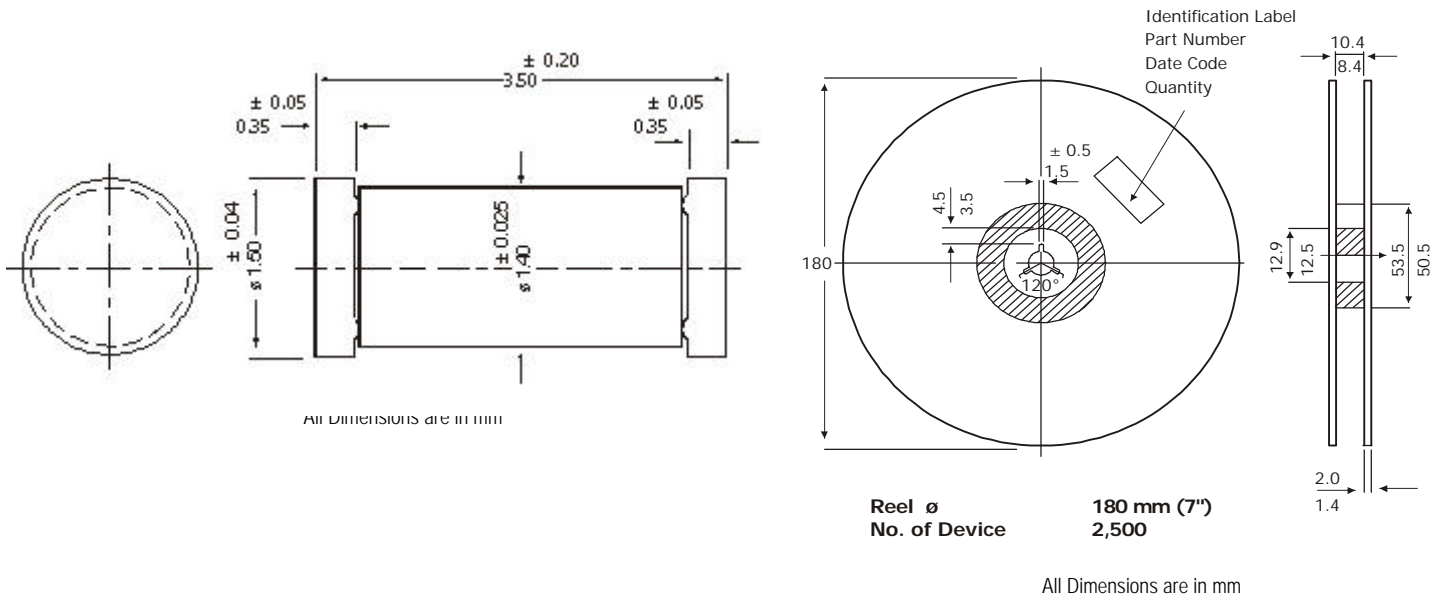
**DIAGRAM 2** :Test circuit for output voltage



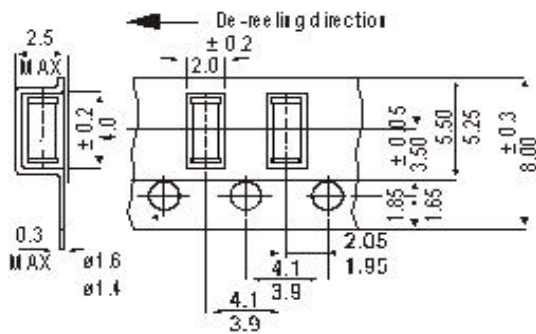
**DIAGRAM 3** : Test circuit see diagram 2.  
Adjust R for  $I_p=0.5A$



SOD 80C (LL-34) Mini MELF Hermetically Sealed Glass Package

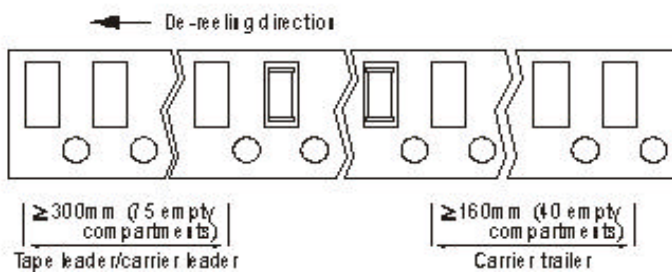


TAPE & REEL



Notes:

1. Maximum of 0.5% of the total number of components per reel may be missing-exclusively at the beginning and at the end of the reel.
2. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.



All Dimensions are in mm

Drawings are not to scale

Packing Detail

| PACKAGE     | STANDARD PACK |                 | INNER CARTON BOX |     | OUTER CARTON BOX                   |             |                     |
|-------------|---------------|-----------------|------------------|-----|------------------------------------|-------------|---------------------|
|             | Details       | Net Weight/Qty  | Size             | Qty | Size                               | Qty         | Gr Wt               |
| SOD-80C T&R | 2.5K/reel     | 225 gm/2.5K pcs | 9" x 9" x 9"     | 40K | 18" x 12" x 10"<br>19" x 19" x 20" | 80K<br>320K | 7.2 kgs<br>28.8 kgs |

### **Disclaimer**

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